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Final Technical Report
on
NASA Grant NSG-8033

A Study of Crystal Growth
by
Solutior Technique

July 1979
Alabama Agricultural and
Mechanical University
Normal, Alabama 35762
Final Technical Report
on
NASA Grant NSG-8033

A Study of Crystal Growth
by
Solution Technique

R. B. LAL
Associate Professor in Physics
Principal Investigator

July 1979
Alabama Agricultural and
Mechanical University
Normal, Alabama 35762
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FOREWORD

The present report, Number AAMU-NAS-004, dated July 1979, of Alabama A and M University, Huntsville, Alabama 35762, is the final report for NASA Grant NSG-8033, entitled, "A Study of Crystal Growth by Solution Technique." This report covers a period from March 1977 to November, 1978. During this period, the P.I. spent a total of four and a half man months time. One undergraduate student, also, spent about 15h/week on this project. From March 1978 till the end of this project, the work on another NASA contract NAS8-32945 was done concurrently. The work on both projects complements each other.

The P.I. is particularly thankful to the NASA Office of University Affairs for the award of this grant which actually evolved into a flight experiment for SL-III mission. The P.I. is now working on the project for the SL-III mission.

The work reported, herein, was done under the technical supervision of Mr. Charles Schafer of NASA/MSFC and his cooperation and comments are gratefully acknowledged.

The author is thankful to Dr. Leon Frazier, Dr. Bessie W. Jones, and Dr. M. C. George for their continued interest and support during the progress of this work.
ABSTRACT

The purpose of this investigation is to study the mechanism of crystal growth by solution technique. A low temperature solution crystal growth setup is developed. Crystals of Triglycine Sulfate (TGS) are grown using this arrangement. Some additional tasks were performed towards fabrication of some experiments for future space flights. As a result of this investigation, a flight experiment proposal was developed and accepted by NASA, MPS program for SL-III mission.
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I. INTRODUCTION

The promise shown by the results of Skylab I and II and the ASTP experiments,\(^1,2\) on materials science are in confirmation of the possibility of processing of materials in space on a routine basis. These results have logically placed an emphasis on simple crystal systems. The results of different flight experiments on various missions have shown excellent promise and have prompted a closer look at the opportunities for more complex and more valuable compound materials.

The NASA materials processing in space (MPS) program is intended to develop applications of space flights in materials science and technology, including both research and manufacturing activities. Its initial goal is to demonstrate the value of space for materials work by achieving significant scientific results and/or developing specific useful materials and products.

Many technologies are dependent on single crystal materials to varying degree. The materials can be processed for making efficient semiconductors for use in the field of communications, materials which will make better superconductors for control and distribution of energy, materials for energy conversion devices, materials for various kinds of detectors, and materials for non-linear optical devices. The eventual processing of materials in space is likely to become major reality with the operational space shuttle in the 80's.
The advantages of weightless environment for materials processing include:

a) absence of buoyant convection, b) absence of density segregation, c) absence of sagging, and d) opportunities of containerless processing. With regard to the growth of crystals, the primary advantage is the absence of buoyant convection. A growing crystal extracts materials from and/or release heat into the surrounding fluid, thereby lowering the fluid's density. So on earth under 1-g conditions, a growing crystal is surrounded by a rising convection current. In most cases, this convection is unstable and gives rise to growth rate instabilities which cause impurity distribution fluctuations and defects such as fluid inclusions.3-7

It would, therefore, be expected that crystals grown in low-gravity environment would be more uniform in composition and have fewer defects than their one-g counterparts.
II. OBJECTIVES

The objective of this investigation is to study the mechanism of crystal growth by the solution technique with special reference to materials for electro-optic devices.

As a part of this investigation, it has always been considered to plan design experiments for space shuttle mission. During this investigation, a flight experiment entitled, "Solution Growth of Crystals in 0-gravity", was proposed to NASA in response to NASA A.O. No. OA-77-3 (copy attached in appendix A). The proposal was accepted by NASA in September 1977 and this experiment is now an approved experiment to fly on the SL-III mission under a separate NASA Contract.

Under NSG-8033, (Supplement) additional tasks for machine shop work towards development of flight experiments for future NASA missions were undertaken.
III. BACKGROUND

In recent years, new applications for non-linear optical devices have been found for ferroelectric single crystals such as Trigycine Sulfate \((\text{NH}_2\text{CH}_2\text{COOH})_3\text{H}_2\text{SO}_4\), crystals of iodate family and others. Single crystals of TGS may be used for infra-red image parametric up-conversion due to their phase match ability and for image tubes for television displays of thermal scenes using their large pyroelectric effect. There is, also, an increasing interest in detectors requiring less cooling or no cooling at all, even if they have low performance, which may lead to systems with greater cost-effectiveness. However, the undisturbed operation of these devices and techniques require single crystals of high optical quality, i.e., of high purity, high homogeneity concerning the physical properties, low density of structural defects and free from inclusions and strains. The long duration orbital flights in the space shuttle era will definitely allow growth of these crystals using solution technique.
IV. CRYSTAL GROWTH FROM SOLUTION

Crystal growth from solutions is simple in principle and has many applications. The technique is particularly useful for growth of materials which have high vapor pressure or decompose irreversibly at the melting point. Crystals will be grown from solution if the solution is supersaturated, i.e. it contains more solute than it can hold in equilibrium with the solid. The growth methods are based on solvent used, because the equipment, range application, problems and approach are to a large extent determined by the choice of the solvent. However, the more fundamental delineation of the methods could be made on the basis of the methods of producing supersaturation. The growth methods can be divided on this basis.

1. Isothermal methods (constant temperature methods)
   A. Solvent evaporation or solvent concentration change (mainly used in aqueous and molten salt growth)
   B. Temperature differential (mainly used in hydrothermal, aqueous and molten salt growth; also includes temperature-gradient zone melting when the gradient is moved through the sample).
   C. Chemical or electrochemical reaction (mainly used in aqueous growth)

2. Non-isothermal methods (temperature variation methods)
   A. Slow cooling (mainly used in aqueous, liquid metal solvent, and molten-salt growth)
   B. Temperature-gradient zone melting (when the gradient is imposed over the whole sample).

IV. 1. Advantages of Growth from Solution

In general solution growth can be accomplished at temperatures considerably below the melting point of the material, and the use of lower temperature alleviates many of the problems associated with the melt growth process.
The main advantages are listed below.

1) The most important advantage of crystal growth from solution is the control that it provides over the temperature of growth. This makes it possible to grow crystals that are unstable at their melting points or that exist in several crystal forms depending upon temperature.

2) A second advantage is the control of viscosity, thus permitting crystals that tend to form glasses when cooled from melts to be grown.

3) Crystals grown from solution usually have well defined faces as compared with those from melts.

4) It avoids strains, reduces vacancy concentration, and sometime reduces dislocations and low angle grain boundaries associated with high temperature growth.

5) Solution growth or low temperature growth is experimentally more convenient. Higher temperature processes are often more demanding on equipment and difficult to control, and harder to keep clean so that products are pure.

Solution growth has had its main success in the preparation of bulk crystals.

There are some disadvantages of a polycomponent growth and they are enumerated below.

1) The additional component will be contaminant and will have solid stability in the grown crystal.

2) Elimination of the additional component at the growing interface will set up an upper limit on rate of growth. Diffusion will be important in this process. This may be an advantage in low-gravity and will be a dominant factor.

3) Because of the concentration gradient at the growing interface, constitutional supercooling will often occur, facets effects, cellular growth and dendritic growth can thus be problems.
The process of crystallization involves simultaneous mass and heat transport between the crystal surface and the surrounding fluid. In almost all cases, this causes a reduction in the density of the fluid. So a growing crystal is usually surrounded by a rising convection current. Chen et al., have demonstrated this in a recent paper. Janssen-van Rosmalen et al., have demonstrated the influence of hydrodynamic environment on the growth and formation of liquid inclusions in large KDP crystals grown by solution technique. It was proposed that veils of liquid inclusions are not a result of starvation in the laminar boundary layer, as suggested earlier, but of depletion in the closed wake at the rear. Growing crystal under normal g-conditions involves in density fluctuations due to gravity driven convection currents due to change in density caused by temperature gradients.

Nearly all crystal growth processes involves both a solid and a fluid component. Since internal binding forces in solids are much larger than 1-g forces, only the properties of the fluid are expected to be significantly influenced by gravity. In the liquid state, intrinsic forces such as cohesion or surface tension are of the same order as 1-g forces, and the familiar properties of liquids are the result of the interaction of intermolecular forces and the gravitational forces. If the gravitational forces are reduced considerably, the behavior of fluids will be determined by molecular forces alone. Thus, the environment of the orbital space-lab will have significant influence on the fluid behavior which is expected to affect the crystal growth process. In the absence of convection, diffusion will be much more significant for the mass transport process.
The process of crystallization from solutions represents a typical phase transition in condensed system. This process is influenced by the creation and structure of the supersaturated solution. The proper crystal growth on the seed inserted into a supersaturated solution is influenced by various factors.

(a) the degree of supersaturation which determines the rate and also the mechanism of growth.

(b) the hydrodynamic conditions in the solution, specially at higher degrees of supersaturation which influences the transfer of the material from the solution to the crystal through the diffusion layer.

(c) the temperature of crystallization.

(d) the quality of the seed used and the chemical purity of the solution.

(e) Another problem in the growth of large, high quality single crystals is the strain induced during growth by the method used in holding the original seed. This is specially evident in solution crystal growth where strain induces optical inhomogeneities, cracks and regions of non-uniform growth rates. Recently, Loiacono et.al\textsuperscript{11} have used a cylindrical seed method to the solution growth of large single crystals of TGS. The method permits the strain free mounting of oriented seed crystals.

(f) finally even the manipulation with the crystal as grown (taking the crystal out of equipment, etc.) can strongly influence its properties.

To investigate the crystallization conditions of TGS in view of growing environment, a crystallizer is required which can be used for growing crystals in absence or with a minimum mechanical disturbance in the growing solution.
Growth of crystals on earth is always accompanied by gravity driven convection currents as well as diffusion fronts.

IV. 2. Effect of Impurity Adsorption on Kinetics of Crystal Growth from Solution.

Recently it has been reported by Davey, that a presence of a third component can often have dramatic effects on the crystal growth kinetics (third component may be an impurity). Adsorption of impurities onto the crystal faces changes the relative surface free energies of the faces and may block sites essential to the incorporation of new solute into the crystal lattice. These effects may result in changes in growth kinetics and hence, habit modification of the crystalline phase.

From the studies of Davey (loc. cit) it seems worth noting the following points in relation to the mechanism of growth rate reduction by impurity adsorption.

a) Impurity adsorption results in the blocking of key sites on the crystal surface.

b) Impurities which bear a structural resemblance to the crystallizing component may be most effective in kink and step sites, while impurities which are structurally dissimilar to the crystallizing component may be limited to ledge sites.

The following requirements of an experimental study may be elucidated.

1. Substantiation of growth mechanism for pure solution.

2. Measurement of growth rate as a function of impurity concentration at a fixed supersaturation.

3. Observation of step systems on faces growing in pure and impure solutions.

4. Measurement of adsorption isotherm of the impurity onto the crystal faces under consideration.

5. The selection of experimental system in which the structural nature of the impurity in solution is known.

The experimental data should then be correlated with different available models of crystal growth in solution.
IV. 3. Uncertainties Regarding Crystal Growth in Low gravity Environment

For a detailed study of the crystal growth processes in low-gravity environment, uncertainties about residual, transient and non-buoyant convection present and their affect on impurity distribution and the formation of defects in the crystal must be considered. Another area of uncertainty is caused by our poor understanding of the basic mechanisms of crystallization. Choices between competing theories depend on accurate measurements of growth rate as a function of the adjacent thermal and concentration gradients and on interface kinetics term. All these measurements, when performed on earth in one-g, are distorted by the effects of convection. Measurement of such data in a fluid in a solution growth experiment will be extremely beneficial to the crystal growth theorists.

Also, affect of low frequency g-levels on the crystal quality is a very important parameter. Displacements produced by low frequency (<10 Hz) g-levels are most harmful to solution crystal growth and must be accounted very carefully.
V. EXPERIMENTAL PROCEDURE

A low temperature solution growth system for growing TGS was designed and fabricated (fig 1). The system includes an outside bath 27.5 cm x 27.5 cm x 17.5 cm made out of 0.9 cm plexiglass. The bath is heated with two vertical quartz heaters each of 350 watts. The fluid in the outside bath which is distilled water is stirred with two stirrers running at 20 rpm using a.c. synchronous motors. The input to the heaters is controlled using a Fisher proportional temperature controller with an accuracy of ±0.01°C. The actual accuracy of the bath is measured at present only to ±0.1°C using NBS calibrated thermometers. The growth solution is kept in a 10 x 10 x 10 cm³ cell made out of 0.6 cm thick plexiglass. The growth cell is surrounded on all sides (except top) by the outside constant temperature bath. The seed crystal is mounted on a specially designed sting which is inserted in the inner cell at a proper time. Details of the sting are given in fig 2. A stainless steel tube is encapsulated by a plexiglass tube machined to fit the stainless tube. A narrow outer jacket is left between the plexiglass and the stainless tube. A desired flow of high purity argon gas can be maintained between this narrow jacket. The desired flow of argon gas is monitored through a flow meter.

*This work was done in conjunction with other NASA Contract NAS 8-32945.*
FIG. 2
DESIGN OF STING

-.35 CM TUBE

1.1 CM HOLE

1.75 CM D

7 CM

.35 CM HOLE

3 CM

7 CM

.6 CM
This serves the purpose of cooling the sting and the seed crystal. The seed crystal is mounted using RTV silicone adhesive at the end of the stainless tube which barely projects out of the plexiglass rod. Two copper-constantan thermo-couples have been installed in the sting. One is behind the seed crystal inside the rod and the other on the outside wall of the sting mounted flush to the surface of the sting. The emf of the two thermocouples is measured using a Keithley 610C electrometer. Omega company copper-constantan 0°C temperature compensator is used for 0°C reference junction.

The inner growth cell is tightly covered with a plexiglass cover to avoid any appreciable loss of liquid due to evaporation.

An overall picture of the experimental set-up is given in fig 3.
V. 1. Test of Thermal Stability of the System

The thermal stability of the growth system was tested for a desired set temperature (between 30°C - 50°C) over a period of 8-12 hours. The stability of the cell temperature greatly depends upon the stirring provided to the outside bath. In the initial run commercially available Fisher Scientific Stirrers were used. It was found that there was a large variation of temperature (±4°C) between the lowest and the top level of the water in the outside bath. The design of the stirrers was modified so that they can stir about 4" of vertical depth of water below the top surface. The bath temperature was then maintained within less than ±0.1°C between different layers of water all around the growth cell. The growth cell was also tested for cool down and heat-up rates. The outside bath can be brought to a desired temperature within ±0.1°C in a period of 20 minutes. Due to the poor conduction of plexiglass the inner cell takes about 2 hours to reach a steady state temperature which was found to be 1°C below the outside bath for a particular cell.
V. 2. Growth of TGS Crystals

Initially seed crystals of TGS were grown by spontaneous nucleation and grown in about 2 or 3% supersaturated solution. Saturated solutions of TGS were prepared from BDH high purity crystalline Triglycine sulfate using double distilled water. Solution is filtered at a temperature of few degree centigrade above the saturation temperature. At the present time crystal growth experiments have been performed in the ferroelectric range which is below the transition temperature of TGS. (Tc $\approx$ 49°C)

Before the start of the experiment the outer bath was set at 37°C. The inner cell filled with 800ml of 36°C saturated solution of TGS. The pH of the solution was measured as 2.4 ±0.1. The cell was left for two hours in the constant temperature bath till its temperature reached a steady value of 36°C. Experiment was initiated by inserting the sting, mounted with a polyhedral seed of TGS using RTV Silicone adhesive, in the solution. A slow purge of prepurified Argon at 2 p.s.i. was maintained through the sting. In this initial run no thermocouple was mounted at the tip of the sting so no temperature reading of the tip and the growth solution were recorded during the growth of the crystal. The Argon gas provided a constant cooling of the sting and a constant supersaturation near the seed crystal. The growth process continued for 26 hours. The crystal grew about four times the size of the seed. The total mass deposited in 26 hours was 2.79679 g. This gives an average growth rate of 0.15 mm/hour, but no precise calculations of average mass transfer coefficient ($k$) has been made at this time. This growth rate is appreciably faster than required for a laminar growth. In this growth, an under-cooling of 1°C was maintained on the tip of the sting. At the end
of the experiment the crystal was removed from the growth solution, dried and stored. Due to some inaccuracy in the saturation curve there were some crystallites seen at the bottom of the growth cell.

No evaluation of the grown sample has been done at this time. It is planned that measurement of dielectric constant, specific heat and domain structure studies will be performed.

Crystal will be grown at different supersaturation, growth temperatures and by varying the pH of the solution. The study of growth of crystals is continuing in another NASA funded project NAS-8-32945.
1. 3. Evaluation Plan

a) Transition Temperature

The transition temperature $T_c$ can be determined for each sample by plotting the temperature variation of the dielectric constant using a General Radio model 1620-AP capacitance measuring assembly (bought under NAS 8-32945).

b) Domain Structure

The dielectric properties of TGS as defined by the electric permittivity $\varepsilon''$ and $\varepsilon'''$ and the spontaneous polarization $P_s$, depend strongly on the conditions in which the crystals are grown. Crystals grown above the Curie point at a constant temperature and the one grown below the Curie point have been found to show different domain structure. Domain structure will be studied in crystals grown in ferroelectric and paraelectric range.

c) Specific Heat Measurements

The relative perfection of ferroelectric crystals can be assessed by the evaluation of the specific heat ($c_p$) curve in the vicinity of a phase transition. In particular, the width and displacement of $c_p$ curve at the transition is significant. Crystalline defects and/or gross impurities produce internal electrical fields and stresses which can cause broadening of the $c_p$ curve and a reduction of $c_p$ at the transition.

The specific heat ($c_p$) for a crystal grown earlier was measured with a Perkin Elmer (DSCI) differential scanning calorimeter.* The measured value of $c_p = 0.3155 \text{cal/g\degree C}$ corresponds to values reported earlier. The precision of the instrument was not adequate to detect any changes in $c_p$ for 0.1\degree C change in temperature. We are trying to improve the sensitivity of $c_p$ measurements.*

*These measurements were made at the Physics Department of the University of Alabama in Huntsville.
VI. ADDITIONAL TASKS UNDER THE GRANT

Under a supplement to the grant, additional tasks were performed as services required in the space processing area towards development of flight experiments for future NASA missions. Such needs were extra machine shop jobs for flight and laboratory experiments. Various pieces of small equipment components were assembled and fabricated under the direction of Mr. Charles Schafer (ES-82) of NASA/MSFC.
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Papers on TGS (cont.)


–30–
Papers on TGS (cont.)


TECHNICAL PROPOSAL

SOLUTION GROWTH OF CRYSTALS

IN O-GRAVITY

Submitted by

Alabama Agriculture and Mechanical University
Normal, AL 35762

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Proposal Summary

SPACE PROCESSING INVESTIGATION FOR
STS MISSION

1. NASA Log. No.:  
2. Proposer's No.:  
3. Discipline: Electronic Material  
4. Estimated Cost:
   First Year: $ 64,107.00
   Total: $255,000.00
5. Investigators:  
   Dr. R. B. Lal -- Principal Investigator  
   Associate Professor in Physics  
   Alabama A. and M. University  
   Normal, AL 35762  
   
   Dr. Roger L. Kroes -- Co-Principal Investigator  
   Space Processing Division  
   ES-74  
   NASA, Marshall Space Flight Center  
   Alabama 35812
6. Proposing Organization  
   Alabama A. and M. University  
   Normal, AL 35762
7. Summary

A series of experiments will be performed in which crystals of high technological importance, such as TGS, will be grown by the solution technique in the micro-gravity environment of Spacelab III. It is intended that the multipurpose fluid phenomena facility developed by NASA/MSFC for use on Spacelab III will be used for growing the crystals. It is expected to grow structurally more homogeneous and large crystals free from inclusions of solution and to obtain data on mass and heat transport in diffusion control growth system.
c. Background and Justification

In recent years new applications for non-linear optical devices have been found for ferroelectric single crystals such as TGS, crystals of iodate family, and others. Single crystals of TGS type \([\text{NH}_2\text{CH}_2\text{COOH}]_3\text{H}_2\text{SO}_4\] may be used for infra-red image parametric up-conversion due to their phase match ability and for image tubes for television displays of thermal scenes using their large pyroelectric effect. There is also an increasing interest in detectors requiring less cooling or no cooling at all, even if they have low performance, which may lead to systems with greater cost-effectiveness. However, the undisturbed operation of these devices and techniques require single crystals of high optical quality, i.e., of high purity, high homogeneity concerning the physical properties, low density of structural defects and free of strains.

It is obvious that solution growth technique will require long duration flights for actual production of bulk crystals. The energy and apparatus requirements will no doubt be within the limits of planned future flights in 1980's, like the Spacelab III.

The principal advantage of low gravity environment is the reduction of gravity induced convective conditions at the growth interface. This should allow close control of composition and growth rate uniformity at the diffusion controlled interface.
d. Objectives

A series of experiments will be performed in which crystals of high technological potential such as TGS (Triglycine sulphate) will be grown by the solution technique in the micro-gravity environment of an orbiting space-craft in Spacelab III. It is intended that the multipurpose fluid phenomena facility presently being developed by NASA/MSFC for use on Spacelab III will be utilized for growing the crystals.

The objectives of growing TGS type crystals in Spacelab III is to confirm the advantages of low-gravity environment for the solution growth, to obtain basic data on crystallization by solution technique, and to obtain data on mass- and heat-transport using the designed optical system of the multipurpose facility. The experiment will be designed to achieve diffusion controlled, steady-state crystallization which will allow a close control of composition and growth rate uniformity at the growth interface. Large single crystals free from defects and stresses may be grown by utilization of the diffusion limited growth conditions in o-gravity.
Plan of Investigation

It is planned to perform a series of experiments in which crystals of high technological importance such as TGS, will be grown from solution in the micro-gravity environment of the Spacelab III.

It is intended that the multipurpose fluid phenomena facility presently being developed by NASA/MSFC for use on Spacelab III will be utilized. The multipurpose fluid phenomena facility (MFPF) will be utilized for the slow cooling method of solution crystal growth. A seed crystal, mounted on the end of a sting will be situated in a saturated growth solution. Heat will be slowly extracted from the crystal through the sting by means of a thermoelectric cooler. The length of the sting should be insulated from the fluid so that heat is extracted at the crystal and not from the solution along the length of the sting. The optical system of the MFPF will be utilized to observe density variations in the solution surrounding the crystal during growth.

Description of the MFPF

The basic equipment for technological research and for growing single crystals from a solution by the method of temperature decrease is being developed by NASA/MSFC. The growth of crystals by this method is possible with substances having a positive and large enough temperature coefficient of solubility in a given solvent. The uniform linear growth of a crystal on a seed requires a variable rate of temperature decrease of the crystallization solution in broad limits. Sufficient accuracy of temperature control is necessary in order to prevent deviations of the so-called metastable zone and thus, the spontaneous formation of minute crystals. For growth of TGS-type crystals this leads to the following basic demands of the crystallization apparatus.
a) Range of operational temperature 30 to 80°C.
b) Precision of temperature control of solution.
c) Programmed decrease of solution temperature.
d) Possibility of fixing seed in different ways with least mechanical shocks.
e) Long-term reliability of the whole equipment.
f) The possibility of removing the crystal from the solution without exposing it to a temperature shock.

The multipurpose fluid phenomena facility developed at NASA/MSFC satisfies most of the above requirements.
Procedure

The sample cell of the MFPF will be filled with a saturated solution of the material to be grown. It is planned that the sting of the MFPF will be made retractable. This is in order to insure that the seed is inserted into the growth solution only after the proper initial growth conditions, such as concentration, temperature, etc., have been established. The outer surface along the length of the sting will be made semi-insulating so that heat will be extracted only from the crystal end and not from the solution along the length of the sting. A properly oriented seed crystal will be mounted at the end of the sting. It may be desirable to mount crystals on the sting with different orientations in order to observe the effect of orientation on growth. In any case the way in which the seed is mounted on the sting will have to be carefully considered so that it does not interfere with an orderly growth.

In the zero-g environment it is anticipated that convective flow in the cell will be greatly reduced or effectively eliminated and that growth will take place by means of a diffusion limited process.

The saturation of the solution in the cell will be checked in advance in the laboratory by inserting a small crystallite near the surface and, with an appropriately adjusted light in MFPF, watching for Schlieren fringes (caused by index-of-refraction variations) associated with the concentration gradients that will exist near a crystallite not in equilibrium with its solution. If the current is descending, it is more dense than the surrounding fluid and the crystal will be dissolving (the solution is undersaturated); if the current is rising, more dense fluid is approaching the crystal from the solution and it is growing (the solution is supersaturated).
Depending upon the results of the test, the temperature of the cell may be adjusted to bring the system closer to equilibrium. The temperature will be maintained at the desired level by a variety of heater-controller arrangement of MFPF.

When the saturation conditions have been established, the temperature of the sample cell is raised slightly (predetermined on ground-based experiment) and the sting with the seed is inserted by simple exchange of the sting. The cell temperature will be kept above saturation for some time (predetermined on ground) until the seed has dissolved slightly as evidenced by the first noticeable rounding at corners and edges. This is done to remove the small individual crystals which may be on the surface as a result of cutting operations and would tend to induce polycrystalline growth. This will also avoid any spurious nucleation on the sides of the cell.

The temperature will then be lowered to saturation temperature and the temperature dropping procedure will begin. Supersaturation will be provided by slow cooling with predetermined cooling rate as calculated from ground based work. The crystal will be grown at a predetermined rate. The optical system of MFPF will monitor the concentration gradient near the seed (caused by the index-of-refraction variations) not in equilibrium with rest of the solution.

Ground-based studies will be made to determine a critical growth rate, so that parasite spontaneous nucleation can be avoided. This will depend upon the supersaturation reached in the solution. Earlier work of Nicolau, on KDP crystals grown by solution technique indicates that parasite nucleation appears when the supersaturation and growth rate exceeds a certain value. Habit modification can be achieved on ground
based work by altering the pH value of the solution.

Another important factor to be taken into account is the removal of the grown crystal from the cell without exposing it to a temperature shock. Finished crystal will be removed from the sting, and depending upon the growth temperature (if much higher than the ambient temperature) will be transferred to a warm air-bath for subsequent slow cooling to avoid thermal shock and cracking.
Characterization Plan

The samples grown in micro-gravity environment will be compared with the best ground-based samples grown in the MFFP and also with the best available commercial samples. The characterization plan can be divided into two broad sections: 1) Receiving, and 2) Identification and Testing Technique.

1. Receiving
   a) The flight samples will be received by the P.I. or Co-P.I. and will be assigned an identification code. The samples will be kept in containers so as to avoid any normal contamination.
   b) Proper log of flight and ground-based samples will be maintained. Proper history of growth for each crystal will be recorded.

2. Identification and Testing Techniques

   Evaluation of crystal quality of flight grown samples will involve various techniques of crystal assessment by using different characterization parameters on ground based samples as well as flight samples.

   Detailed plan will be made in accordance with the final selection of material for growth in micro-gravity environment.

   Conventional crystal characterization techniques such as, x-ray diffraction, dislocation density measurements, optical microscopy for discontinuities and inclusions, infra-red absorption studies, dielectric loss measurements, and electrical properties, can be used for crystal assessment. For TGS type crystals data can be compared with ground-based samples and from the available literature.
REFERENCES


f. **Expected Results**

The following results are expected from a series of experiments in which crystals of high technological importance such as TGS will be grown from solution in the micro-gravity environment of the Spacelab III utilizing the MFPF under development at NASA/MSFC.

1. The experiments should allow close control of composition and growth rate uniformity at the diffusion controlled interface.

2. To grow structurally more homogeneous and large crystals free from inclusions of the solution.

3. To obtain data on mass and heat transport using the optical system of the MFPF.

4. To obtain information on growth rates on different crystallographic axes of the seed crystal.

5. To grow crystals of controlled morphology.
g. Key Personnel

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